

# SHINDENGEN

## 3 Phase Bridge Diode

Diode Module

**S30VTA80**

**800V 30A**

### FEATURES

- Dual In-Line Package
- Compact 3 phase bridge
- High IFSM
- Applicable to mount on glass-epoxy substrate (VTA type)

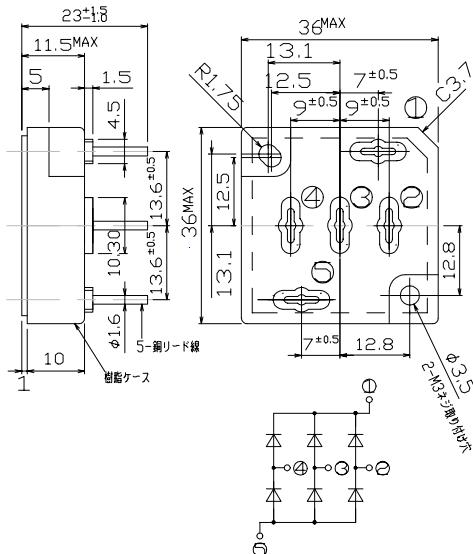
### APPLICATION

- Big Power Supply
- Air conditioner
- Factory Automation, Inverter

### OUTLINE DIMENSIONS

Case : SVTA

(Unit : mm)



### RATINGS

#### ● Absolute Maximum Ratings (If not specified $T_c=25^\circ\text{C}$ )

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	$T_{stg}$		-40~150	$^\circ\text{C}$
Operating Junction Temperature	$T_j$		150	$^\circ\text{C}$
Maximum Reverse Voltage	$V_{RM}$		800	V
Average Rectified Forward Current	$I_O$	50Hz sine wave, R-load With heatsink, $T_c=121^\circ\text{C}$	30	A
Peak Surge Forward Current	$I_{FSM}$	50Hz sine wave, Non-repetitive 1cycle peak value, Rating of per diode, $T_j=25^\circ\text{C}$	400	A
Current Squared Time	$I^2t$	$1\text{ms} \leq t < 10\text{ms}$ $T_c=25^\circ\text{C}$	800	$\text{A}^2\text{s}$
Dielectric Strength	$V_{dis}$	Terminals to case, AC 1 minute	2	kV
Mounting Torque	$T_{OR}$	(Recommended torque : 0.6N·m)	0.8	N·m

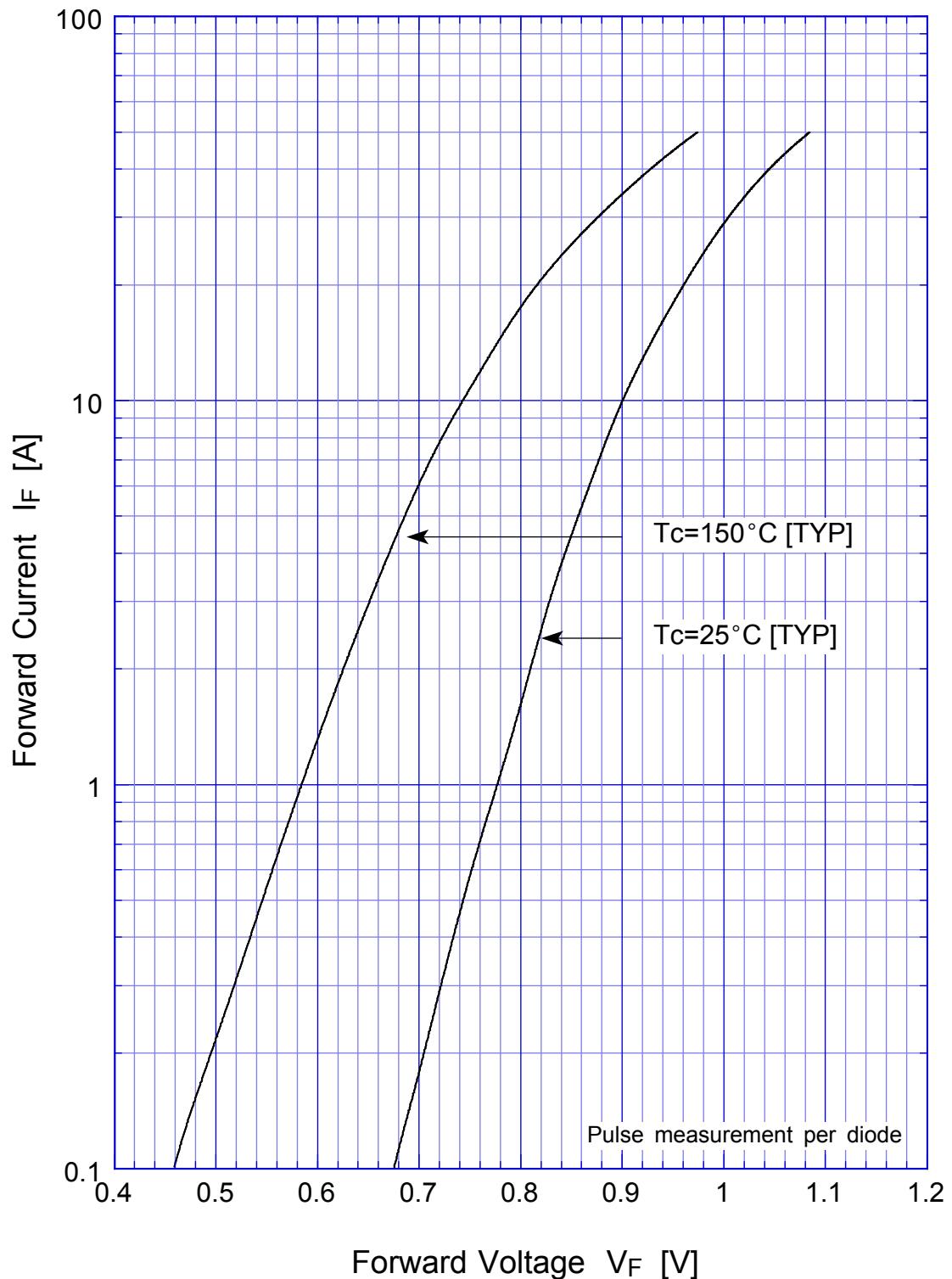
#### ● Electrical Characteristics (If not specified $T_c=25^\circ\text{C}$ )

Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	$V_F$	$I_F=10\text{A}$ , Pulse measurement, Rating of per diode	Max.1.05	V
Reverse Current	$I_R$	$V_R=V_{RM}$ , Pulse measurement, Rating of per diode	Max.10	$\mu\text{A}$
Thermal Resistance	$\theta_{jc}$	junction to case	Max.0.5	$^\circ\text{C}/\text{W}$

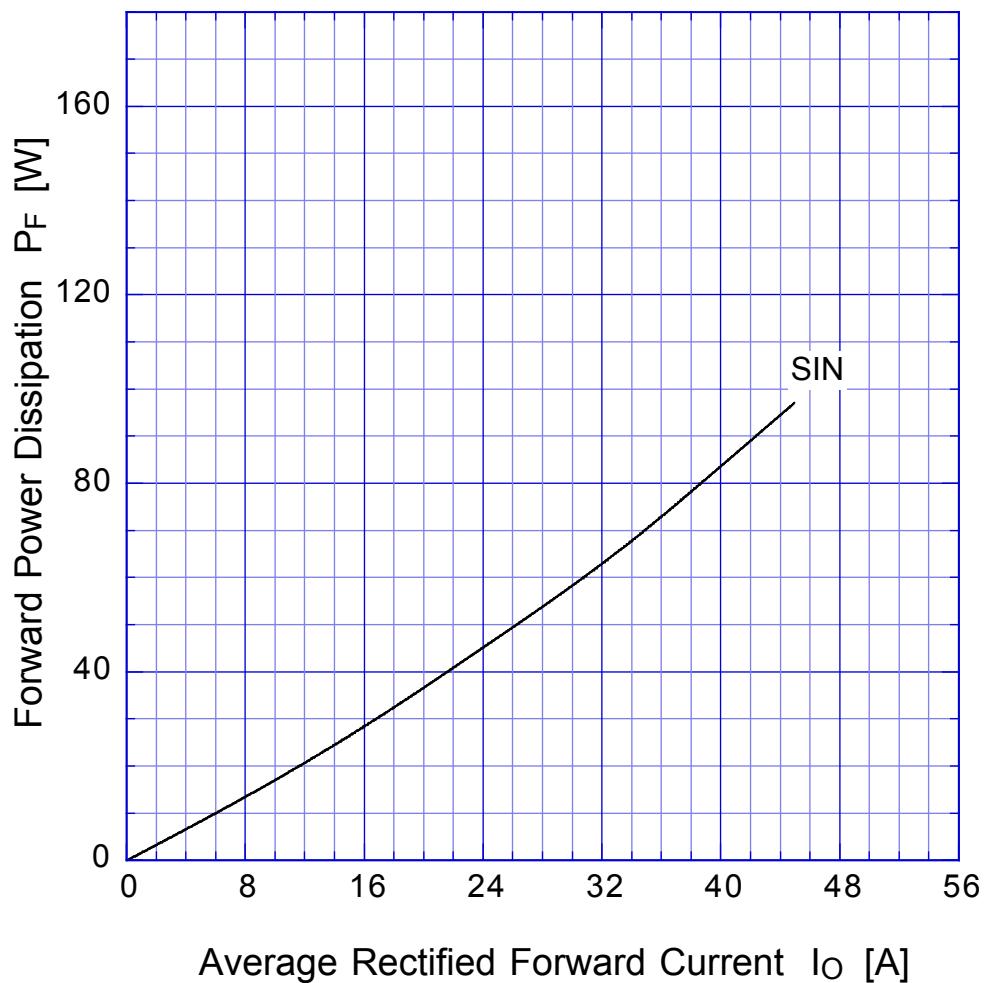
# S30VTAx

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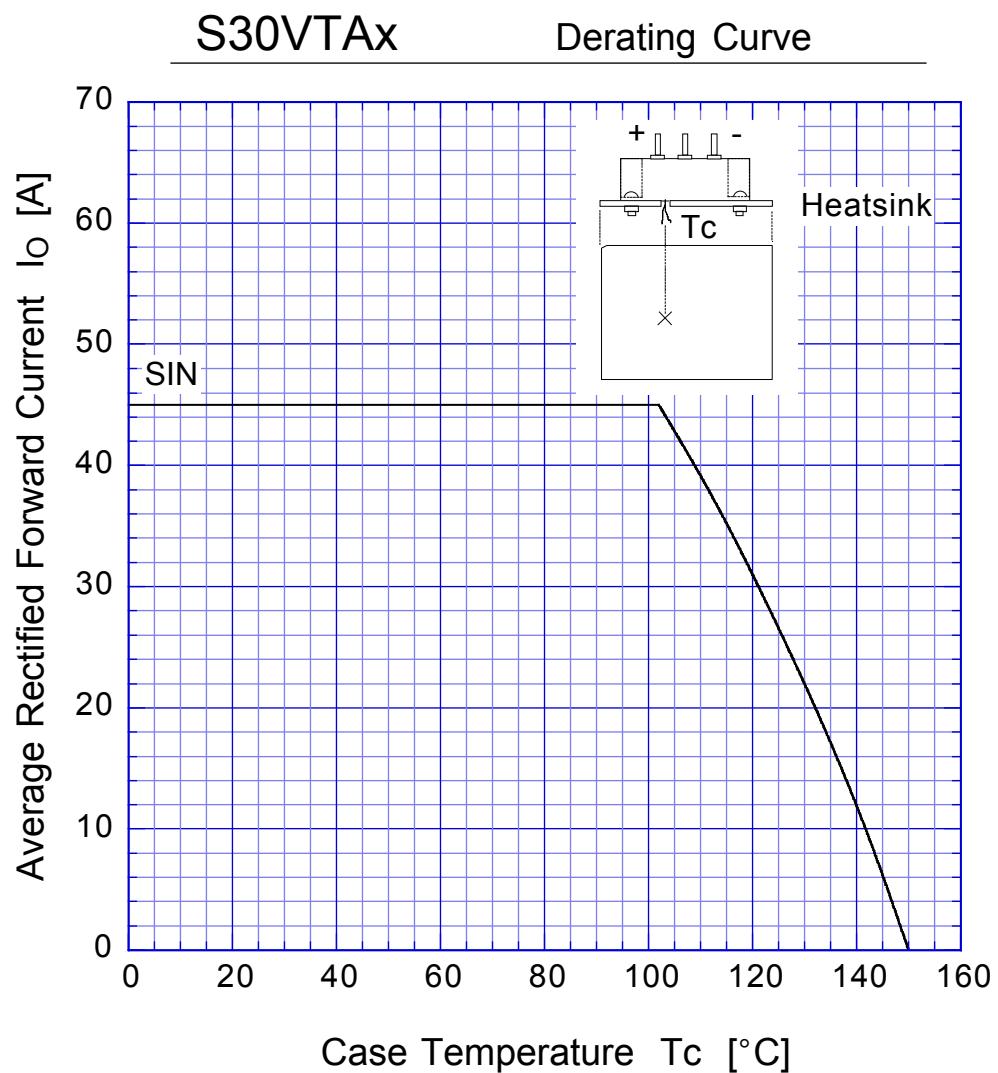
## Forward Voltage



## S30VTAx Forward Power Dissipation



$T_j = 150^\circ\text{C}$   
Sine wave



Sine wave  
R-load  
with heatsink

# S30VTAx

## Peak Surge Forward Capability

